

Data Sheet July 1999 File Number 4610.1

# High Reliability, Radiation Hardened Octal Buffer/Line Driver, Three-State, Inverting

Intersil's Satellite Applications Flow<sup>TM</sup> (SAF) devices are fully tested and guaranteed to 100kRAD total dose. These QML Class T devices are processed to a standard flow intended to meet the cost and shorter lead-time needs of large volume satellite manufacturers, while maintaining a high level of reliability.

The Intersil ACTS240T is a Radiation Hardened High Reliability, High-Speed CMOS/SOS Octal Buffer/Line Driver with three-state outputs having two active low enable inputs. Each enable input controls a set of four inverting buffer/line drivers. A HIGH on the enable input places the outputs in a high impedance state.

## **Specifications**

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

Detailed Electrical Specifications for the ACTS240T are contained in SMD 5962-96717. A "hot-link" is provided from our website for downloading.

www.intersil.com/spacedefense/newsafclasst.asp

Intersil's Quality Management Plan (QM Plan), listing all Class T screening operations, is also available on our website.

www.intersil.com/quality/manuals.asp

## **Ordering Information**

ORDERING NUMBER	PART NUMBER	TEMP. RANGE (°C)
5962R9671701TRC	ACTS240DTR	-55 to 125
5962R9671701TXC	ACTS240KTR	-55 to 125

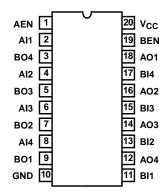
NOTE: Minimum order quantity for -T is 150 units through distribution, or 450 units direct.

## Features

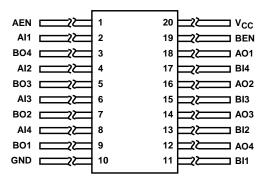
- QML Class T, Per MIL-PRF-38535
- · Radiation Performance
- Gamma Dose (γ) 1 x 10<sup>5</sup> RAD(Si)
- Latch-Up Free Under Any Conditions
- Single Event Upset (SEU) Immunity: <1 x 10<sup>-10</sup> Errors/Bit/Day (Typ)
- SEU LET Threshold . . . . . . . . > 100 MEV-cm<sup>2</sup>/mg
- 1.25 Micron Radiation Hardened SOS CMOS
- Significant Power Reduction Compared to ALSTTL Logic
- DC Operating Voltage Range..... 4.5V to 5.5V
- · Input Logic Levels
  - $V_{II} = 0.8V Max$
  - $V_{IH} = V_{CC/2} Min$
- Fast Propagation Delay . . . . . . 17.5ns (Max), 12ns (Typ)

## **Pinouts**

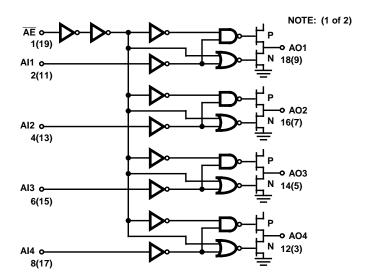
#### ACTS240T (SBDIP), CDIP2-T20 TOP VIEW



#### ACTS240T (FLATPACK), CDFP4-F20 TOP VIEW



## Functional Diagram



TRUTH TABLE

INPUTS		OUTPUT
ĀĒ, BĒ	Aln, Bln	AOn, BOn
L	L	Н
L	Н	L
Н	Х	Z

NOTE: H = High Voltage Level, L = Low Voltage Level, X = Immaterial, Z = High Impedance

## Die Characteristics

## **DIE DIMENSIONS:**

 $(2540 \mu m \ x \ 2540 \mu m \ x \ 533 \mu m \ \pm 51 \mu m)$  $100 \ x \ 100 \ x \ 21 mils \ \pm 2 mil$ 

## **METALLIZATION:**

Type: Al Si Cu

Thickness: 10.0kÅ ±2kÅ

#### **SUBSTRATE POTENTIAL:**

Unbiased (Silicon on Sapphire) Bond Pad #20 (V<sub>CC</sub>) First

Bond Pad #10 (Gnd) Uses Two Bond Wires Bond Pad #20 (V<sub>CC</sub>) Uses Two Bond Wires

## **BACKSIDE FINISH:**

Sapphire

## PASSIVATION:

Type: Silox (S<sub>i</sub>O<sub>2</sub>) Thickness: 8.0kÅ ±1.0kÅ

## **WORST CASE CURRENT DENSITY:**

< 2.0e5 A/cm<sup>2</sup>

#### TRANSISTOR COUNT:

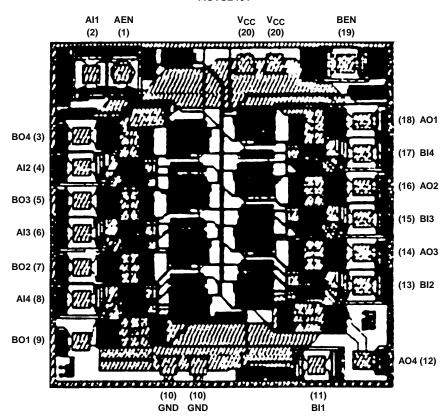
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#### PROCESS:

**CMOS SOS** 

## Metallization Mask Layout

#### ACTS240T



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